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**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

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MAR 28 2005

**Complete if Known**

Application Number	10/810,962
Filing Date	March 26, 2004
First Named Inventor	RUECKES et al.
Art Unit	<del>2827</del> 2827
Examiner Name	TBA Huan Hoang
Attorney Docket Number	112020.145YS2 NAN-21

Sheet 1 of 4

**U. S. PATENT DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code <sup>2</sup> (if known)			
HH		US 2002/0130311 A1	09-19-2002	LIEBER et al.	
		US 2002/0130353 A1	09-19-2002	LIEBER et al.	
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		US-2004/0214366 A1	10-28-2004	SEGAL et al.	
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HH		US-6,559,468 B1	05-06-2003	KUEKES et al.	

Examiner Signature	Huan Hoang	Date Considered	5/1/05
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<b>STATEMENT BY APPLICANT</b> (Use as many sheets as necessary)		Application No. <u>10/810,962</u> Filing Date <u>3/26/04</u>	
		First Named Inventor <u>RUECKES et al.</u> Art Unit <u>2827</u> Examiner Name <u>IBA Huan Hoang</u> Attorney Docket Number <u>112020.145YS2 NAN-21</u>	
Sheet	<u>2</u>	of	<u>4</u>

HU	US-6,574,130	09-04-2003	SEGAL et al.
	US-6,643,165	11-04-2003	SEGAL et al.
	US-6,673,424 B1	01-06-2004	LINDSAY
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HU	US-6,784,028	08-31-2004	RUECKES et al.

FOREIGN PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code <sup>2</sup> (if known)			
HU		WO 01/44796 A1	06-21-2001	Board of Trustees of the Leland Stanford Junior. University.	
HU		WO 01/03208 A1	01-11-2001	President and Fellows of Harvard College	

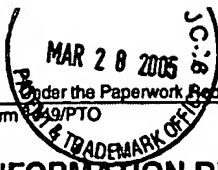
NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, volume-issue number(s), page(s), publisher, city and/or country where published.	T <sup>2</sup>
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Examiner Signature	<u>Huan Hoang</u>	Date Considered	<u>5/1/05</u>
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Substitute for form PTO		<b>Complete if Known</b>	
<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> (Use as many sheets as necessary)		Application Number	10/810,962
		Filing Date	March 26, 2004
		First Named Inventor	RUECKES et al.
		Art Unit	<del>2827</del> 2827
		Examiner Name	TBA Huan Hoang
		Attorney Docket Number	112020.145YS2 NAN-21
Sheet	3 ✓	of	4

144	A6	CUI, J.B. et al., "Carbon Nanotube Memory Devices of High Charge Storage Stability." <i>Appl. Phys. Lett.</i> , 2002, Vol. 81(17) 3260-3262.	
	A7	DAI, H. et al., "Controlled Chemical Routes to Nanotube Architectures, Physics, and Devices." <i>J. Phys. Chem. B</i> , 1999, Vol. 103, 111246-11255.	
	A8	DEHON, A., "Array-Based Architecture for FET-Based, Nanoscale Electronics." <i>IEEE Transactions on Nanotechnology</i> , 2003, Vol. 2(1) 23-32.	
	A9	DEQUESNES, M. et al., "Calculation of pull-in voltages for carbon-nanotube-based nanoelectromechanical switches." <i>Nanotechnology</i> , 2002, Vol. 13, 120-131.	
	A10	DEQUESNES, M. et al., "Simulation of carbon nanotube-based nanoelectromechanical switches." <i>Computational Nanoscience and Nanotechnology</i> , 2002, 383-386.	
	A11	FAN, S. et al., "Carbon nanotube arrays on silicon substrates and their possible application." <i>Physica E</i> , 2000, Vol. 8, 179-183.	
	A12	FARAJIAN, A. A. et al., "Electronic transport through bent carbon nanotubes: Nanoelectromechanical sensors and switches." <i>Phys. Rev. B</i> , 2003, Vol. 67, 205423-1 - 205423-6.	
	A13	FISCHER, J.E. et al., "Magnetically aligned single wall carbon nanotube films: Preferred orientation and anisotropic transport properties." <i>Journal of Appl. Phys.</i> , 2003, Vol. 93(4) 2157-2163.	
	A14	FRANKLIN, N. R. et al., "Integration of suspended carbon nanotube arrays into electronic devices and electromechanical systems." <i>Appl. Phys. Lett.</i> , 2002, Vol. 81(5) 913-915.	
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	A19	RADOSAVLJEVIC, M. et al., "Nonvolatile molecular memory elements based on ambipolar nanotube field effect transistors." <i>Nano Letters</i> , 2002, Vol. 2(7) 761-764.	
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Examiner Signature	Huan Hoang	Date Considered	5/1/05
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<p style="text-align: center;"><b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> (Use as many sheets as necessary)</p>			<p>Application No. <u>10/810,962</u></p>		
			<p>Filing Date <u>March 26, 2004</u></p>		
			<p>First Named Inventor <u>RUECKES et al.</u></p>		
			<p>Art Unit <u>2827</u></p>		
			<p>Examiner Name <u>TBA Huan Hoang</u></p>		
Sheet	4	of	4	<p>Attorney Docket Number <u>112020.145YS2 NAN-21</u></p>	

NR	A21	RUECKES, T., et al., "Carbon Nanotube-Based Nonvolatile Random Access Memory for Molecular Computing" <i>Science</i> , 2000, Vol. 289, 94-97.	
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	A24	TANS, S. et al., "Room-temperature transistor based on a single carbon nanotube." <i>Nature</i> , 1998, Vol. 393, 49-52.	
	A25	TOUR, J. M. et al., "NanoCell Electronic Memories." <i>J. Am. Chem Soc.</i> , 2003, Vol. 125, 13279-13283.	
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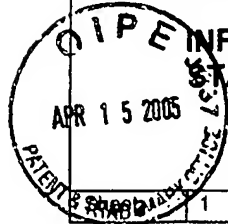
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Application No.	10/810,962
Filing Date	March 26, 2004
First Named Inventor	RUECKES, et al.
Art Unit	2818 2827
Examiner Name	IBA Huan Hoang
Attorney Docket Number	112020.145 US2 NAN-21

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1 of 1

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HL		US-6,548,841	04-15-2003	FRAZIER et al.	
		US-6,803,840	10-12-2004	HUNT et al.	
HL		US-6,809,465	10-26-2004	JIN	
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		Number-Kind Code <sup>2(f) known</sup>			
HL		WO 04/065657	08-05-2004	Nantero, Inc.	

**NON PATENT LITERATURE DOCUMENTS**

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Signature

Huan Hoang

Date  
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